Continental Device India Limited







SOT-23 Formed SMD Package

BCW71 BCW72

SILICON PLANAR EPITAXIAL TRANSISTORS

N-P-N transistors

Marking

BCW71 = KI

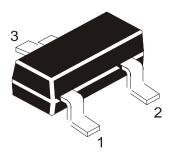
BCW72 = K2

Pin configuration

1 = BASE 2 = EMITTER

3 = COLLECTOR





ABSOLUTE MAXIMUM RATINGS

			BCW71		BCW72	
D.C. current gain at $T_j = 25$ °C		>	110		200	
$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	h_{FE}	<	220		450	
Collector-base voltage (open emitter)	V_{CB0}	max.		<i>50</i>	V	
Collector-emitter voltage (open base)	V_{CE0}	max.		45	V	
Collector current (peak value)	I_{CM}	max.		<i>200</i>	mA	
Total power dissipation up to $T_{amb} = 25$ °C	P_{tot}	max.		<i>250</i>	mW	
Junction temperature	T_{j}	max.		<i>150</i>	° C	
Transition frequency at $f = 35$ MHz	•					
$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	f_T	typ.		<i>300</i>	MHz	
Noise figure at $R_S = 2 k\Omega$						
$I_C = 200 \ \mu A; \ V_{CE} = 5 \ V;$						
f = 1 kHz; B = 200 Hz	$\boldsymbol{\mathit{F}}$	<		10	dB	

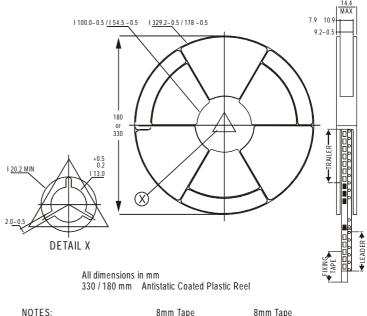
BCW71 BCW72

RATINGS (at $T_A = 25$ °C unless otherwise spec	rified)				
Limiting values					
Collector-base voltage (open emitter)			V_{CB0}	max.	50 V
Collector-emitter voltage (open base)					
$I_C = 2 \text{ mA}$			V_{CE0}	max.	45 V
Emitter-base voltage (open collector)			V_{EB0}	max.	5 V
Collector current (d.c.)			I_C	max.	100 mA
Collector current (peak value)			I_{CM}	max.	200 mA
Total power dissipation up to $T_{amb} = 25 ^{\circ}C$			P_{tot}	max.	<i>250</i> mW
Storage temperature			T_{stg}	-55 to	+150 °C
Junction temperature			T_j	max.	150 ° C
THERMAL RESISTANCE					
From junction to ambient			$R_{th\ j-a}$	=	<i>500</i> K/W
CHARACTERISTICS					
$T_i = 25$ °C unless otherwise specified					
Collector cut-off current					
$I_E = 0$; $V_{CB} = 20 \text{ V}$			I_{CB0}	<	100 nA
$I_E = 0$; $V_{CB} = 20 \text{ V}$; $T_j = 100 ^{\circ}\text{C}$			I_{CB0}	<	10 μA
Base emitter voltage					
$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$			V_{BE}	550 to	700 mV
Saturation voltages					
$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$				typ.	120 mV
<i>y</i> b 4/4			V_{CEsat}	<	250 mV
					750 mV
			V _{BEsat}		750 IIIV
$I_C = 50 \text{ mA}; l_B = 2.5 \text{ mA}$			V_{CEsat}	typ.	210 mV
10 - 00 mz 1, 1 _B - 2,0 mz 1			V_{BEsat}	typ.	850 mV
D.C. current gain			BCW71	E	BCW72
$I_C = 10 \ \mu A; \ V_{CE} = 5 \ V$	h_{FE}	typ.	90		<i>150</i>
		>	110		200
$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	h_{FE}	<	220		450
Collector capacitance at $f = 1$ MHz					
$I_E = I_e = 0; \ V_{CB} = 10 \ V$	C_{c}	typ.		2,5	рF
Transition frequency at $f = 35 \text{ MHz}$					•
$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	f_T	typ.		300	MHz
Noise figure at $R_S = 2 k\Omega$					
$I_C = 200 \ \mu A; \ V_{CE} = 5 \ V$					
f = 1 kHz; B = 200 Hz	$\boldsymbol{\mathit{F}}$	<		10	dB

SOT-23 Formed SMD Package

2.50 +/- 0.10 +/- 0.05 0.62 1.30+/-0.025 +/-0.05 0.62 +/-0.025 1.90 cL 3 - 0.05 - 1.30 +/- 0.05 0.62 I← 0.62 0.08 0.08 MIN MIN PARTING LINE RO.08 0.06 0.21 2.50 +/-0.10

SOT-23 Package Reel Information Reel specifications for Packing (13"/7" reels)

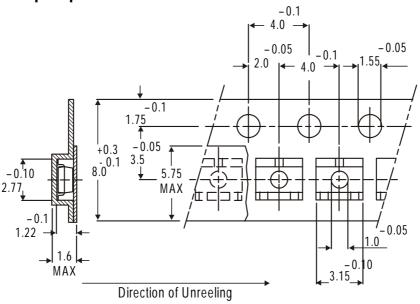


NOTES: 8mm Tape 8mm Tape Size of Reel 330 mm (13") 180 mm (7")

No. of Devices 10,000 Pcs 3,000 Pcs

- 1. The bandolier of 330 mm reel contains at least 10,000 devices.
- 2. The bandolier of 180 mm reel contains at least 3,000 devices.
- No more than 0.5% missing devices / reel. 50 empty compartments for 330 mm reel.
 empty compartments for 180 mm reel.
- Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.
- The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Tape Specification for SOT-23 Surface Mount Device



All dimensions in mm

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5" 9" x 9" x 9"	12.0K 51.0K	17" x 15" x 13.5" 19" x 19" x 19"	192.0K 408.0K	12 kgs 28 kgs	
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs	

Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
 - 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119
email@cdil.com www.cdilsemi.com